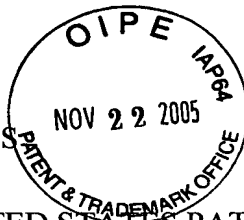


DOCKET NO: 251023US2S



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
YOSHIHISA IWATA ET AL. : EXAMINER: PHAN, T. Q.  
SERIAL NO: 10/807,454 :  
FILED: MARCH 24, 2004 : GROUP ART UNIT: 2827  
FOR: SEMICONDUCTOR MEMORY :  
DEVICE HAVING MEMORY  
CELLS INCLUDING  
FERROMAGNETIC FILMS AND  
CONTROL METHOD THEREOF

AMENDMENT UNDER 37 C.F.R. § 1.111

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated July 25, 2005, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 6 of this paper.

**Amendments to the Drawings** begin on page 17 of this paper and include an attached replacement sheet.

**Remarks/Arguments** begin on page 18 of this paper.